L	Hits	Search Text	DB	Time stamp
Number				0001100105
1	1	5854135.pn.	USPAT;	2004/02/06
			EPO; JPO;	08:16
			IBM_TDB	0004/00/06
2	0	(contact or via) same (dielectric or	USPAT;	2004/02/06
		insulating) same endpoint same bias same	EPO; JPO;	08:18
		voltage	IBM_TDB	
3	303	(contact or via) and (dielectric or	USPAT;	2004/02/06
		insulating) and endpoint and bias and	EPO; JPO;	09:43
		voltage	IBM_TDB	
4	1		USPAT	2004/02/06
				09:32
5	1		USPAT	2004/02/06
				09:32
6	14	(SAC or "self aligned contact") same	USPAT;	2004/02/06
		endpoint	EPO; JPO;	09:39
			IBM_TDB	
7	297	(SAC or "self aligned contact") and	USPAT;	2004/02/06
		endpoint	EPO; JPO;	09:39
			IBM TDB	
8	54	(SAC or "self aligned contact") and	USPAT;	2004/02/06
		endpoint and bias	EPO; JPO;	09:39
		•	IBM TDB	
9	301	(contact or opening) and via and	USPAT;	2004/02/06
		(dielectric or insulating) and endpoint	EPO; JPO;	10:20
		and bias	IBM TDB	
10	217	(contact or opening) and via and gate and	USPAT;	2004/02/06
		spacer and endpoint	EPO; JPO;	10:20
			IBM TDB	
11	23	(SAC or "self aligned contact") and	USPAT;	2004/02/06
		endpoint and etch\$3 and bias	EPO; JPO;	10:45
			IBM TDB	
12	11	bias same compensation same (voltage or	USPAT;	2004/02/06
		volts) same etch\$3	EPO; JPO;	10:46
		, salas salas salas s	IBM TDB	